



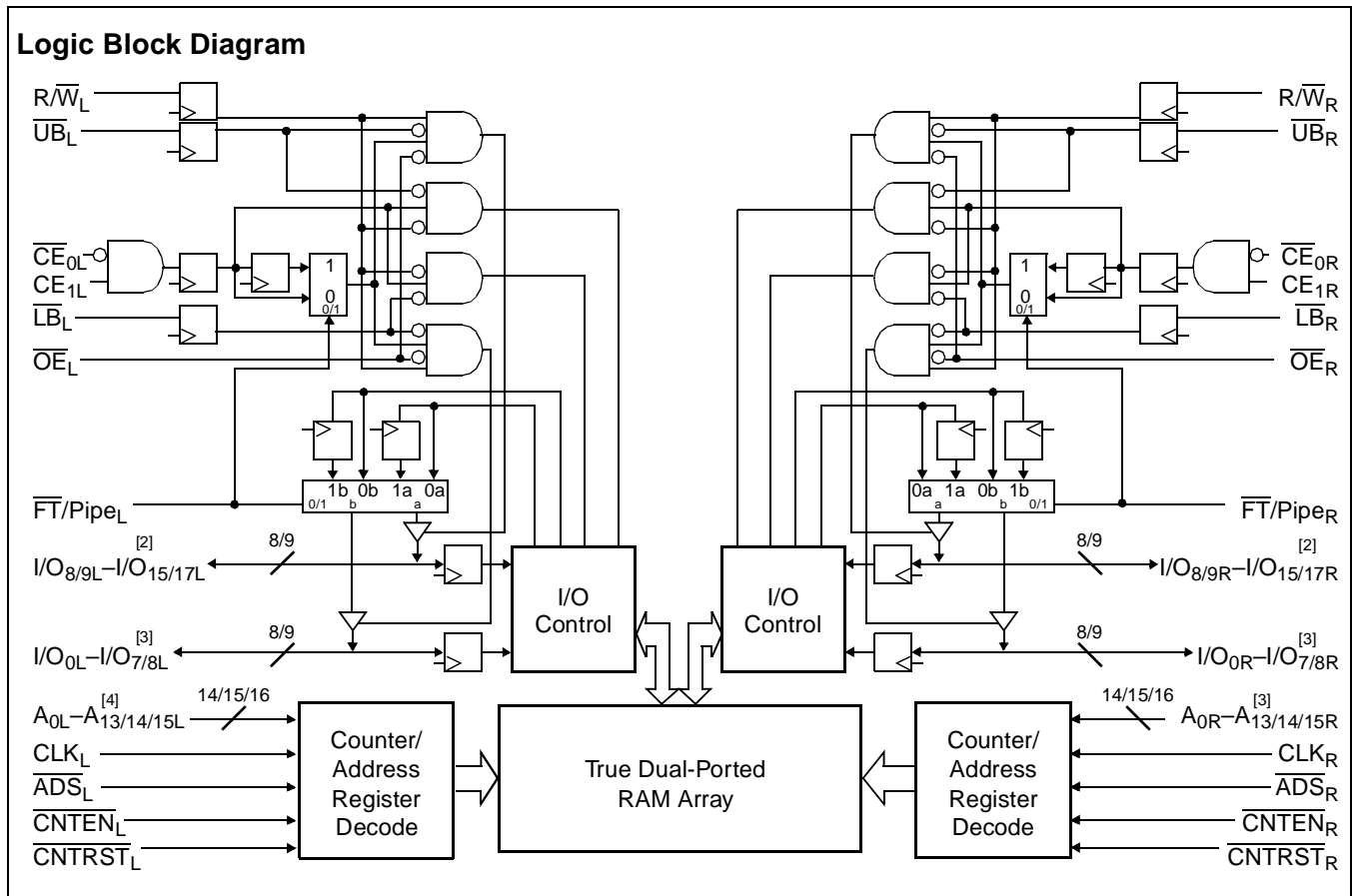
PRELIMINARY

CY7C09269V/79V/89V
CY7C09369V/79V/89V

3.3V 16K/32K/64K x 16/18 Synchronous Dual-Port Static RAM

Features

- True Dual-Ported memory cells which allow simultaneous access of the same memory location
- 6 Flow-Through/Pipelined devices
 - 16K x 16/18 organization (CY7C09269V/369V)
 - 32K x 16/18 organization (CY7C09279V/379V)
 - 64K x 16/18 organization (CY7C09289V/389V)
- 3 Modes
 - Flow-Through
 - Pipelined
 - Burst
- Pipelined output mode on both ports allows fast 83-MHz operation
- 0.35-micron CMOS for optimum speed/power
- High-speed clock to data access 7.5^[1]/9/12 ns (max.)
- 3.3V Low operating power
 - Active= 115 mA (typical)
 - Standby= 10 μ A (typical)
- Fully synchronous interface for easier operation
- Burst counters increment addresses internally
 - Shorten cycle times
 - Minimize bus noise
 - Supported in Flow-Through and Pipelined modes
- Dual Chip Enables for easy depth expansion
- Upper and Lower Byte Controls for Bus Matching
- Automatic power-down
- Commercial and Industrial temperature ranges
- Available in 100-pin TQFP



Notes:

1. Call for Availability.
2. I/O₈-I/O₁₅ for x16 devices; I/O₉-I/O₁₇ for x18 devices.
3. I/O₀-I/O₇ for x16 devices. I/O₀-I/O₈ for x18 devices.
4. A₀-A₁₃ for 16K; A₀-A₁₄ for 32K; A₀-A₁₅ for 64K devices.

For the most recent information, visit the Cypress web site at www.cypress.com



Functional Description

The CY7C09269V/79V/89V and CY7C09369V/79V/89V are high speed 3.3V synchronous CMOS 16K, 32K, and 64K x 16/18 dual-port static RAMs. Two ports are provided permitting independent, simultaneous access for reads and writes to any location in memory.^[5] Registers on control, address, and data lines allow for minimal set-up and hold times. In pipelined output mode, data is registered for decreased cycle time. Clock to data valid $t_{CD2} = 9$ ns (pipelined). Flow-through mode can also be used to bypass the pipelined output register to eliminate access latency. In flow-through mode data will be available $t_{CD1} = 18$ ns after the address is clocked into the device. Pipelined output or flow-through mode is selected via the $\overline{FT/PIPE}$ pin.

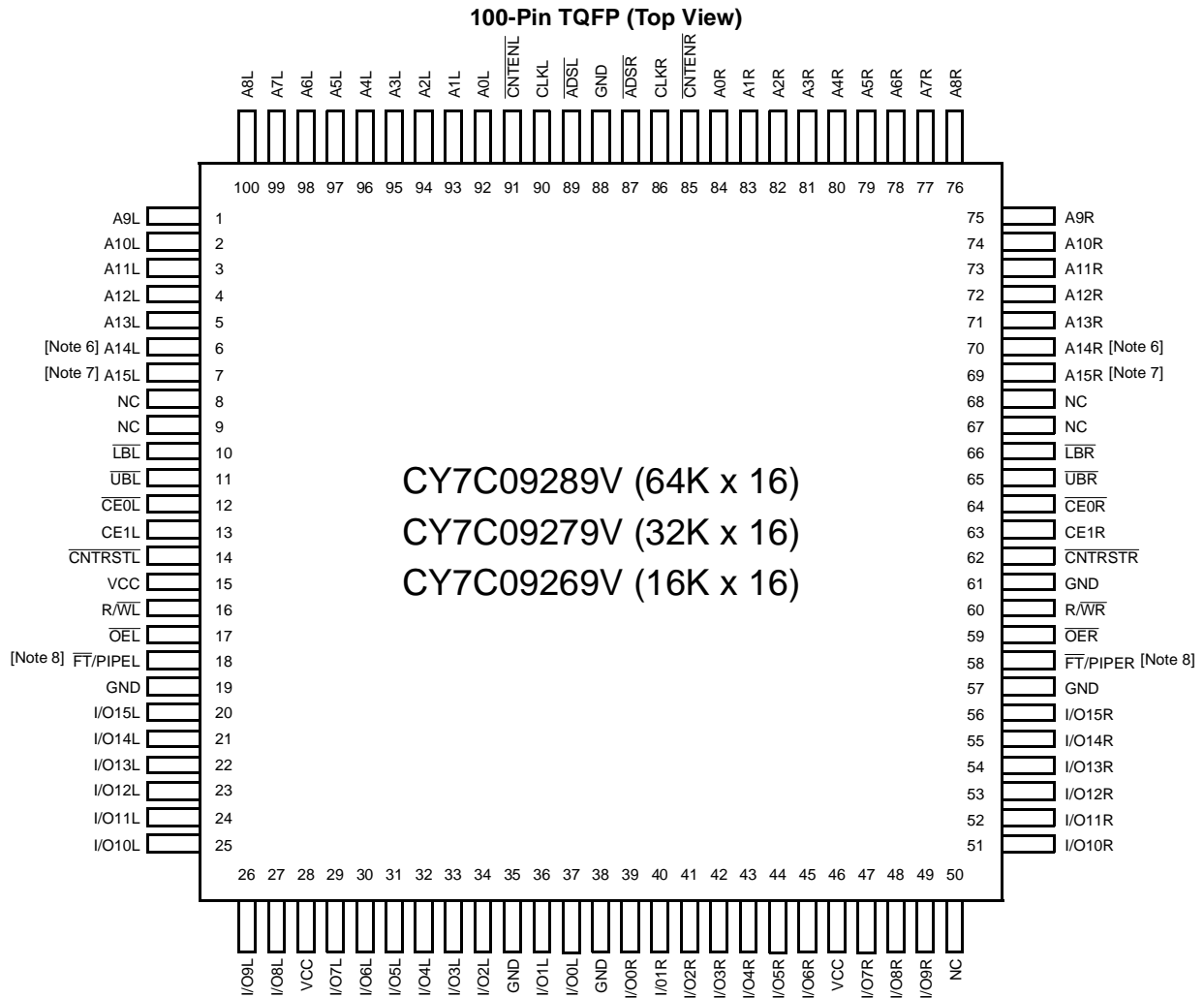
Each port contains a burst counter on the input address register. The internal write pulse width is independent of the LOW to HIGH transition of the clock signal. The internal write pulse is self-timed to allow the shortest possible cycle times.

A HIGH on \overline{CE}_0 or LOW on CE_1 for one clock cycle will power down the internal circuitry to reduce the static power consumption. The use of multiple Chip Enables allows easier banking of multiple chips for depth expansion configurations. In the pipelined mode, one cycle is required with \overline{CE}_0 LOW and CE_1 HIGH to reactivate the outputs.

Counter enable inputs are provided to stall the operation of the address input and utilize the internal address generated by the internal counter for fast interleaved memory applications. A port's burst counter is loaded with the port's address strobe (\overline{ADS}). When the port's count enable (\overline{CNTEN}) is asserted, the address counter will increment on each LOW to HIGH transition of that port's clock signal. This will read/write one word from/into each successive address location until \overline{CNTEN} is deasserted. The counter can address the entire memory array and will loop back to the start. Counter reset (\overline{CNTRST}) is used to reset the burst counter.

All parts are available in 100-pin Thin Quad Plastic Flatpack (TQFP) packages.

Pin Configurations

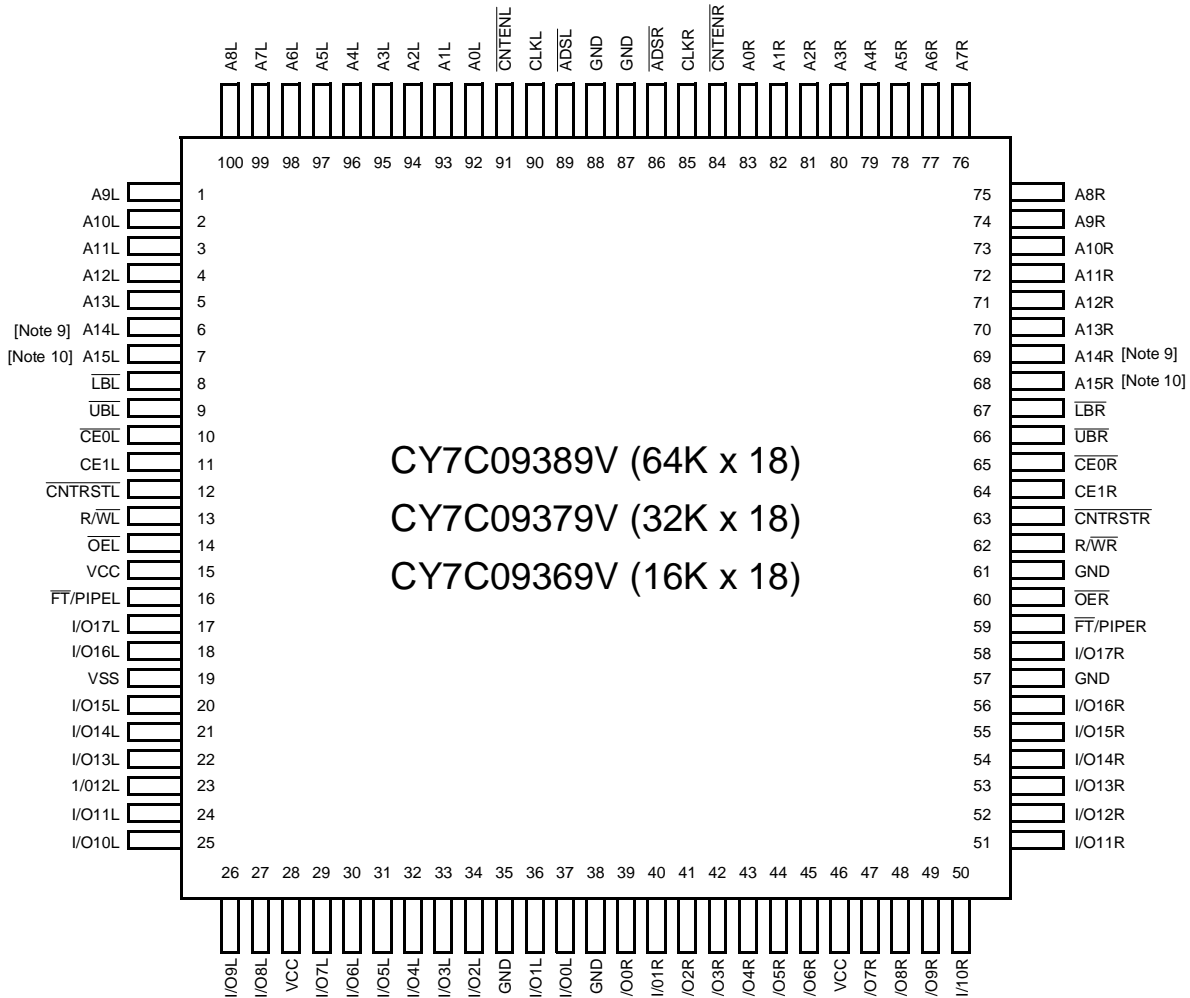


Notes:

5. When writing simultaneously to the same location, the final value cannot be guaranteed.
6. This pin is NC for CY7C09269V.
7. This pin is NC for CY7C09269V and CY7C09279V.
8. For CY7C09269V and CY7C09279V, pin #18 connected to V_{CC} is pin compatible to an IDT 5V x16 pipelined device; connecting pin #18 and #58 to GND is pin compatible to an IDT 5V x16 flow-through device.

Pin Configurations (continued)

100-Pin TQFP (Top View)



Selection Guide

	CY7C09269V/79V/89V CY7C09369V/79V/89V -7^[1]	CY7C09269V/79V/89V CY7C09369V/79V/89V -9	CY7C09269V/79V/89V CY7C09369V/79V/89V -12
f _{MAX2} (MHz) (Pipelined)	83	67	50
Max Access Time (ns) (Clock to data, Pipelined)	7.5	9	12
Typical Operating Current I _{CC} (mA)	155	135	115
Typical Standby Current for I _{SB1} (mA) (Both ports TTL Level)	25	20	20
Typical Standby Current for I _{SB3} (µA) (Both ports CMOS level)	10 µA	10 µA	10 µA

Shaded area contains advance information.

Notes:

- 9. This pin is NC for CY7C09369V.
- 10. This pin is NC for CY7C09369V and CY7C09379V.



Pin Definitions

Left Port	Right Port	Description
A _{0L} -A _{15L}	A _{0R} -A _{15R}	Address Inputs (A ₀ -A ₁₄ for 32K, A ₀ -A ₁₃ for 16K devices).
\overline{ADS}_L	\overline{ADS}_R	Address Strobe Input. Used as an address qualifier. This signal should be asserted LOW to access the part using an externally supplied address. Asserting this signal LOW also loads the burst counter with the address present on the address pins.
$\overline{CE}_{0L}, CE_{1L}$	$\overline{CE}_{0R}, CE_{1R}$	Chip Enable Input. To select either the left or right port, both \overline{CE}_0 AND CE_1 must be asserted to their active states ($\overline{CE}_0 \leq V_{IL}$ and $CE_1 \geq V_{IH}$).
CLK _L	CLK _R	Clock Signal. This input can be free running or strobed. Maximum clock input rate is f _{MAX} .
CNTEN _L	CNTEN _R	Counter Enable Input. Asserting this signal LOW increments the burst address counter of its respective port on each rising edge of CLK. CNTEN is disabled if ADS or CNTRST are asserted LOW.
\overline{CNTRST}_L	\overline{CNTRST}_R	Counter Reset Input. Asserting this signal LOW resets the burst address counter of its respective port to zero. CNTRST is not disabled by asserting ADS or CNTEN.
I/O _{0L} -I/O _{17L}	I/O _{0R} -I/O _{17R}	Data Bus Input/Output (I/O ₀ -I/O ₁₅ for x16 devices).
\overline{LB}_L	\overline{LB}_R	Lower Byte Select Input. Asserting this signal LOW enables read and write operations to the lower byte. (I/O ₀ -I/O ₈ for x18, I/O ₀ -I/O ₇ for x16) of the memory array. For read operations both the \overline{LB} and \overline{OE} signals must be asserted to drive output data on the lower byte of the data pins.
\overline{UB}_L	\overline{UB}_R	Upper Byte Select Input. Same function as \overline{LB} , but to the upper byte (I/O _{8/9L} -I/O _{15/17L}).
\overline{OE}_L	\overline{OE}_R	Output Enable Input. This signal must be asserted LOW to enable the I/O data pins during read operations.
R/ \overline{W}_L	R/ \overline{W}_R	Read/Write Enable Input. This signal is asserted LOW to write to the dual port memory array. For read operations, assert this pin HIGH.
$\overline{FT}/PIPE_L$	$\overline{FT}/PIPE_R$	Flow-Through/Pipelined Select Input. For flow-through mode operation, assert this pin LOW. For pipelined mode operation, assert this pin HIGH.
GND		Ground Input.
NC		No Connect.
V _{CC}		Power Input.

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature -65°C to +150°C

Ambient Temperature with

Power Applied -55°C to +125°C

Supply Voltage to Ground Potential -0.5V to +4.6V

DC Voltage Applied to

Outputs in High Z State -0.5V to V_{CC}+0.5V

DC Input Voltage -0.5V to V_{CC}+0.5V

Output Current into Outputs (LOW) 20 mA

Static Discharge Voltage >1100V

Latch-Up Current >200mA

Operating Range

Range	Ambient Temperature	V _{CC}
Commercial	0°C to +70°C	3.3V ± 300 mV
Industrial	-40°C to +85°C	3.3V ± 300 mV

Shaded area contains advance information.

Electrical Characteristics Over the Operating Range

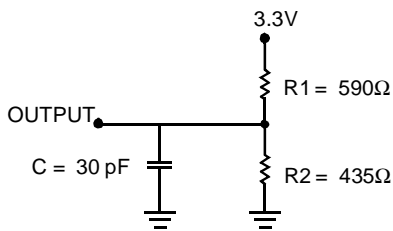
Symbol	Parameter	CY7C09269V/79V/89V CY7C09369V/79V/89V									Units
		-7 ^[1]			-9			-12			
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
V _{OH}	Output HIGH Voltage (V _{CC} =Min, I _{OH} =-4.0 mA)	2.4			2.4			2.4			V
V _{OL}	Output LOW Voltage (V _{CC} =Min, I _{OH} = +4.0 mA)			0.4			0.4			0.4	V
V _{IH}	Input HIGH Voltage	2.2			2.2			2.2			V
V _{IL}	Input LOW Voltage			0.8			0.8			0.8	V
I _{OZ}	Output Leakage Current	-10		10	-10		10	-10		10	μA
I _{CC}	Operating Current (V _{CC} =Max, I _{OUT} =0 mA) Outputs Disabled	Com'l.	155	275		135	230		115	180	mA
		Indust.				185	300		155	250	mA
I _{SB1}	Standby Current (Both Ports TTL Level) ^[11] \overline{CE}_L & $\overline{CE}_R \geq V_{IH}$, f=f _{MAX}	Com'l.	25	85		20	75		20	70	mA
		Indust.				35	85		30	80	mA
I _{SB2}	Standby Current (One Port TTL Level) ^[11] \overline{CE}_L $\overline{CE}_R \geq V_{IH}$, f=f _{MAX}	Com'l.	105	165		95	155		85	140	mA
		Indust.				105	165		95	150	mA
I _{SB3}	Standby Current (Both Ports CMOS Level) ^[11] \overline{CE}_L & $\overline{CE}_R \geq V_{CC} - 0.2V$, f=0	Com'l.	10	100		10	100		10	100	μA
		Indust.				10	100		10	100	μA
I _{SB4}	Standby Current (One Port CMOS Level) ^[11] \overline{CE}_L $\overline{CE}_R \geq V_{IH}$, f=f _{MAX}	Com'l.	95	125		85	115		75	100	mA
		Indust.				95	125		85	110	mA

Shaded area contains advance information.

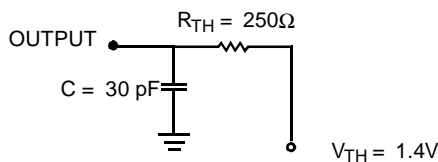
Capacitance

Parameter	Description	Test Conditions	Max.	Unit
C _{IN}	Input Capacitance	T _A = 25°C, f = 1 MHz,	10	pF
C _{OUT}	Output Capacitance	V _{CC} = 3.3V	10	pF

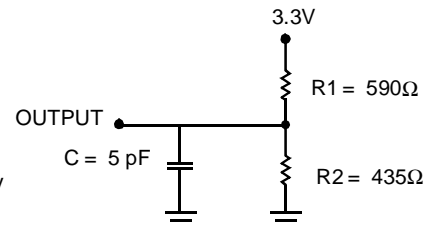
AC Test Loads



(a) Normal Load (Load 1)

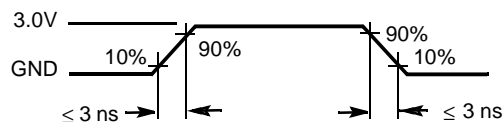


(b) Thévenin Equivalent (Load 1)



(c) Three-State Delay (Load 2)
(Used for t_{CKLZ}, t_{OLZ}, & t_{OHZ} including scope and jig)

ALL INPUT PULSES



Note:

11. \overline{CE}_L and \overline{CE}_R are internal signals. To select either the left or right port, both \overline{CE}_0 AND CE_1 must be asserted to their active states ($\overline{CE}_0 \leq V_{IL}$ and $CE_1 \geq V_{IH}$).



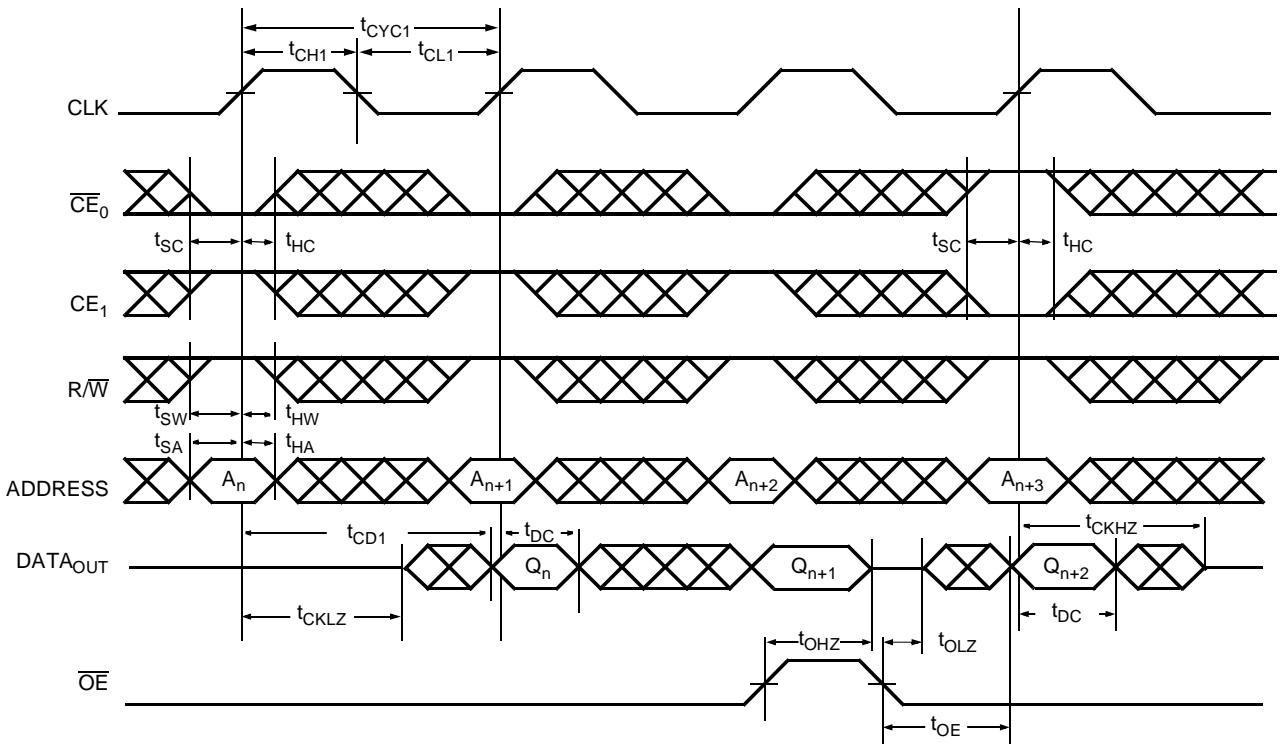
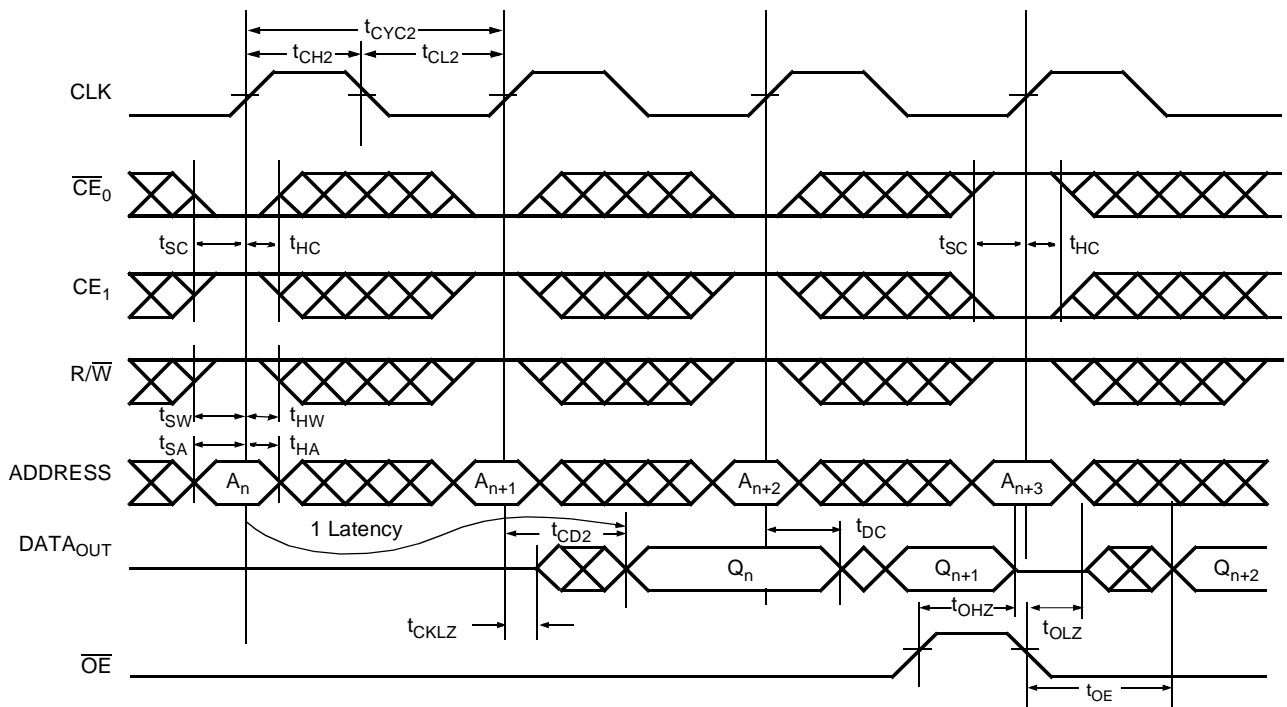
Switching Characteristics Over the Operating Range

Symbol	Parameter	CY7C09269V/79V/89V CY7C09369V/79V/89V						Units
		-7 ^[1]		-9		-12		
		Min	Max	Min	Max	Min	Max	
f _{MAX1}	f _{Max} Flow-Through		45		40		33	MHz
f _{MAX2}	f _{Max} Pipelined		83		67		50	MHz
t _{CYC1}	Clock Cycle Time - Flow-Through	22		25		30		ns
t _{CYC2}	Clock Cycle Time - Pipelined	12		15		20		ns
t _{CH1}	Clock HIGH Time - Flow-Through	7.5		12		12		ns
t _{CL1}	Clock LOW Time - Flow-Through	7.5		12		12		ns
t _{CH2}	Clock HIGH Time - Pipelined	5		6		8		ns
t _{CL2}	Clock LOW Time - Pipelined	5		6		8		ns
t _R	Clock Rise Time		3		3		3	ns
t _F	Clock Fall Time		3		3		3	ns
t _{SA}	Address Set-Up Time	4		4		4		ns
t _{HA}	Address Hold Time	0		1		1		ns
t _{SC}	Chip Enable Set-Up Time	4		4		4		ns
t _{HC}	Chip Enable Hold Time	0		1		1		ns
t _{SW}	R/ \bar{W} Set-Up Time	4		4		4		ns
t _{HW}	R/ \bar{W} Hold Time	0		1		1		ns
t _{SD}	Input Data Set-Up Time	4		4		4		ns
t _{HD}	Input Data Hold Time	0		1		1		ns
t _{SAD}	\overline{ADS} Set-Up Time	4		4		4		ns
t _{HAD}	\overline{ADS} Hold Time	0		1		1		ns
t _{SCN}	\overline{CNTEN} Set-Up Time	4.5		5		5		ns
t _{HCN}	\overline{CNTEN} Hold Time	0		1		1		ns
t _{SRST}	\overline{CNRST} Set-Up Time	4		4		4		ns
t _{HRST}	\overline{CNRST} Hold Time	0		1		1		ns
t _{OE}	Output Enable to Data Valid		9		10		12	ns
t _{OLZ} ^[12,13]	\overline{OE} to Low Z	2		2		2		ns
t _{OHZ} ^[12,13]	\overline{OE} to High Z	1	7	1	7	1	7	ns
t _{CD1}	Clock to Data Valid - Flow-Through		18		20		25	ns
t _{CD2}	Clock to Data Valid - Pipelined		7.5		9		12	ns
t _{DC}	Data Output Hold After Clock HIGH	2		2		2		ns
t _{CKZ} ^[12,13]	Clock HIGH to Output High Z	2	9	2	9	2	9	ns
t _{CKZ} ^[12,13]	Clock HIGH to Output Low Z	2		2		2		ns
Port to Port Delays								
t _{CWDD}	Write Port Clock HIGH to Read Data Delay		35		40		40	ns
t _{CCS}	Clock to Clock Set-Up Time		10		15		15	ns

Shaded area contains advance information.

Notes:

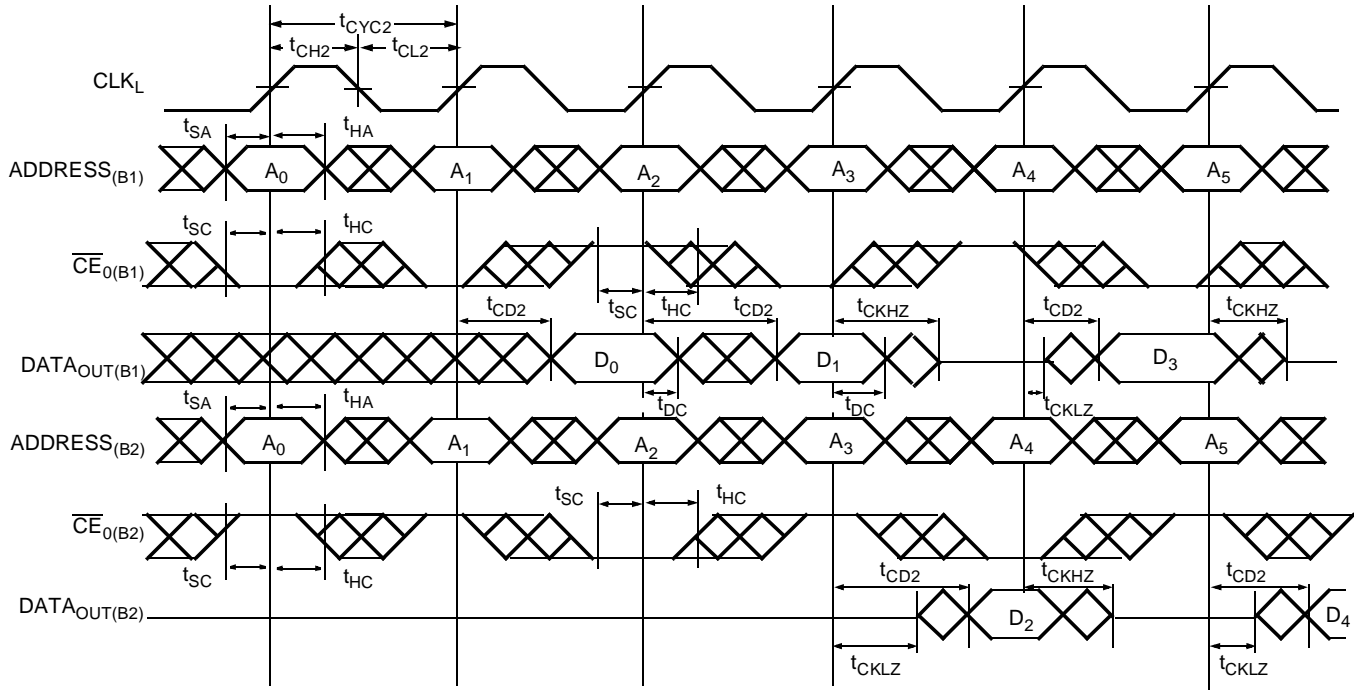
- 12. Test conditions used are Load 2.
- 13. This parameter is guaranteed by design, but it is not production tested.

Switching Waveforms
Read Cycle for Flow-Through Output ($\overline{FT}/PIPE = V_{IL}$)^[14,15,16,17]

Read Cycle for Pipelined Operation ($\overline{FT}/PIPE = V_{IH}$)^[14,15,16,17]

Notes:

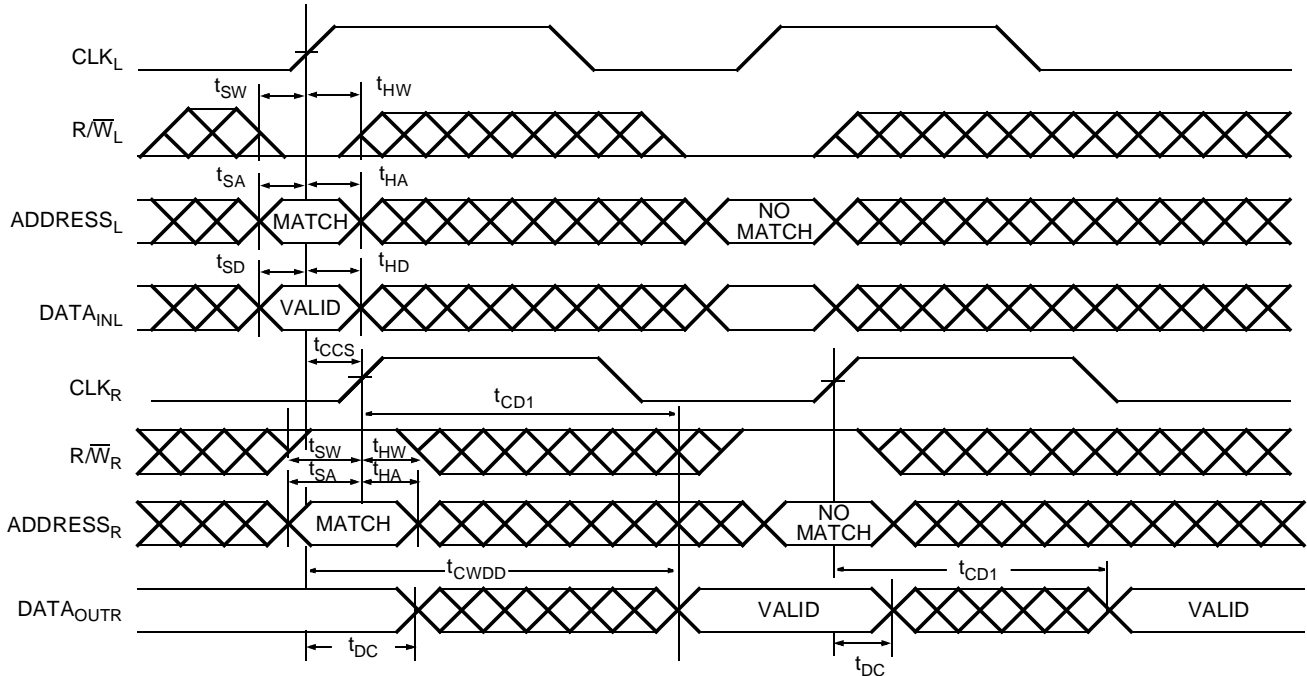
14. \overline{OE} is asynchronously controlled; all other inputs are synchronous to the rising clock edge.
15. $ADS = V_{IL}$, $CNTEN$ and $CNTRST = V_{IH}$.
16. The output is disabled (high-impedance state) by $\overline{CE}_0 = V_{IH}$ or $CE_1 = V_{IL}$ following the next rising edge of the clock.
17. Addresses do not have to be accessed sequentially since $ADS = V_{IL}$ constantly loads the address on the rising edge of the CLK. Numbers are for reference only.

Switching Waveforms (continued)

Bank Select Pipelined Read^[18,19]

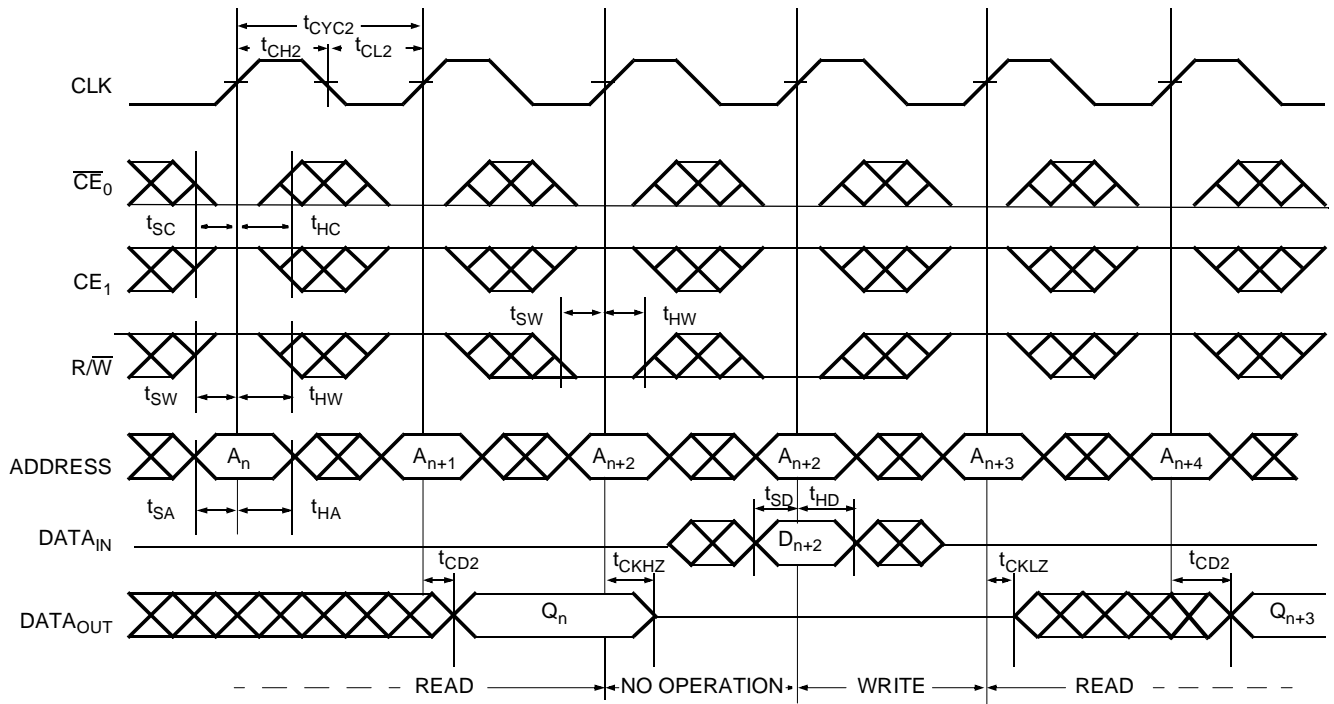
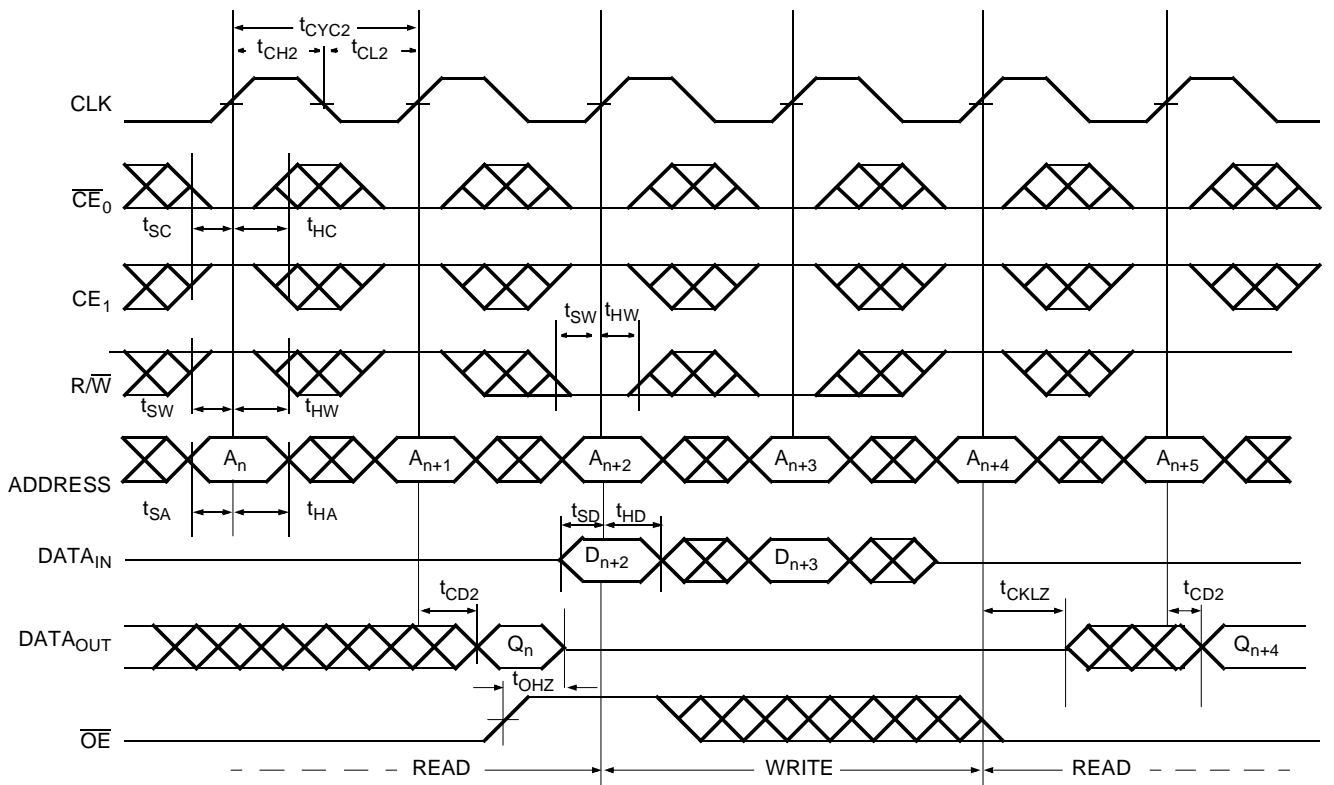


Left Port Write to Flow-Through Right Port Read^[20,21,22,23]

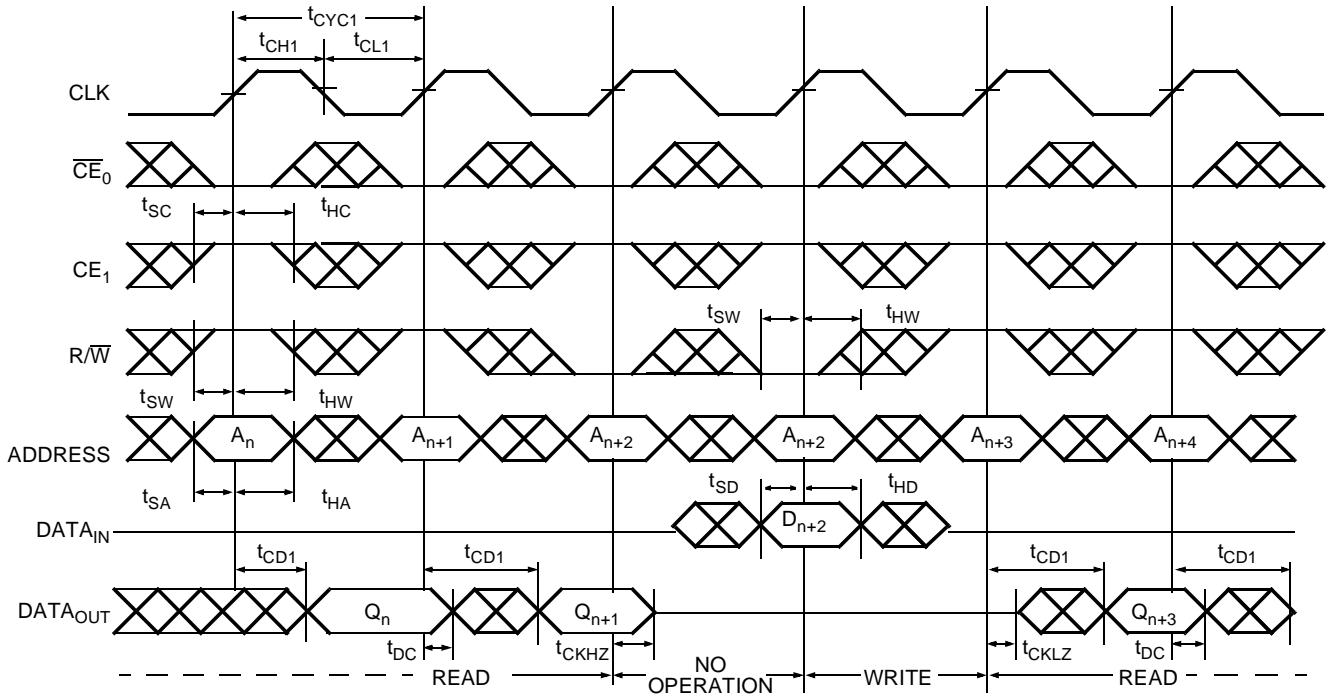
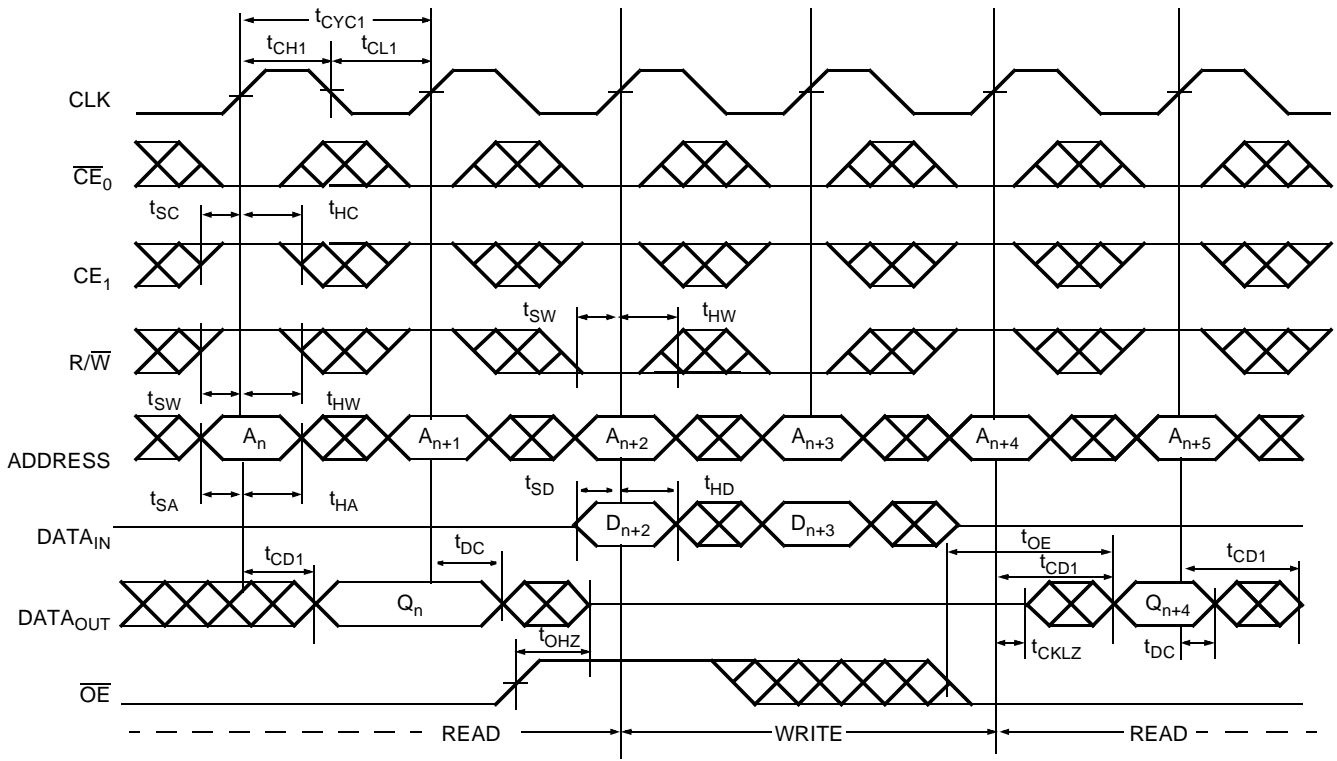


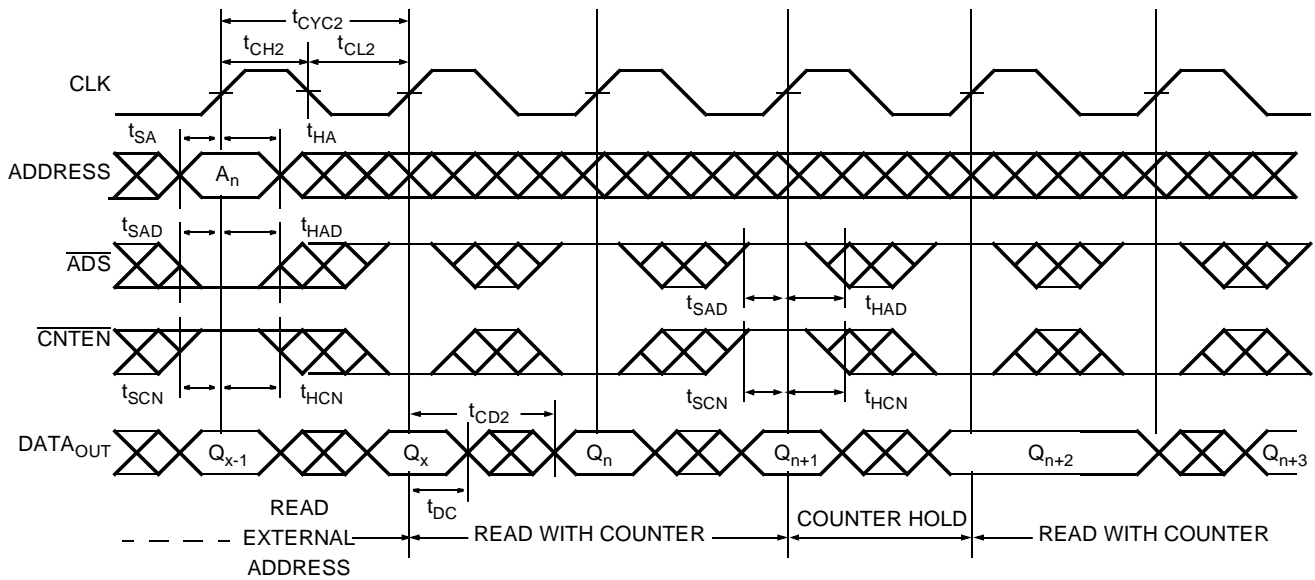
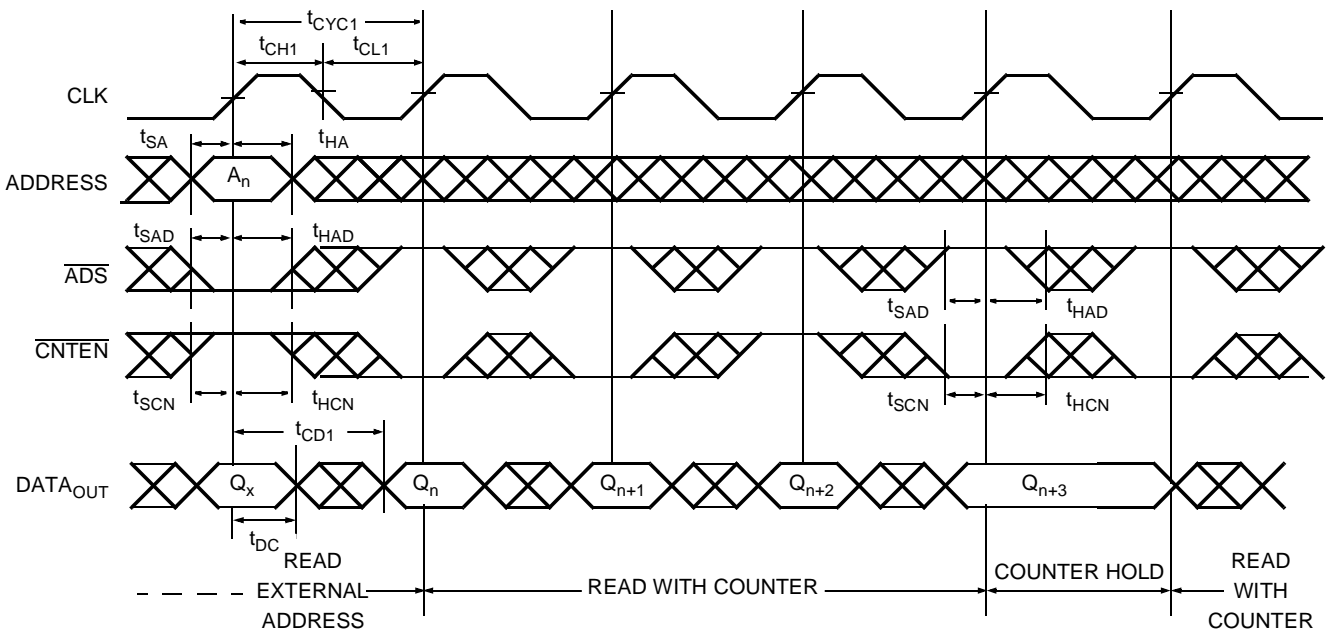
Notes:

- 18. In this depth expansion example, B1 represents Bank #1 and B2 is Bank #2; Each Bank consists of one Cypress dual-port device from this datasheet. ADDRESS_(B1) = ADDRESS_(B2).
- 19. UB, LB, OE and ADS = V_{IL}; CE_{1(B1)}, CE_{1(B2)}, R/W, CNTEN, and CNTRST = V_{IH}.
- 20. The same waveforms apply for a right port write to flow-through left port read.
- 21. CE₀, UB, LB, and ADS = V_{IL}; CE₁, CNTEN, and CNTRST = V_{IH}.
- 22. OE = V_{IL} for the Right Port, which is being read from. OE = V_{IH} for the Left Port, which is being written to.
- 23. If t_{CCS} ≤ maximum specified, then data from right port READ is not valid until the maximum specified for t_{CWDD}. If t_{CCS} > maximum specified, then data is not valid until t_{CCS} + t_{CD1}. t_{CWDD} does not apply in this case.

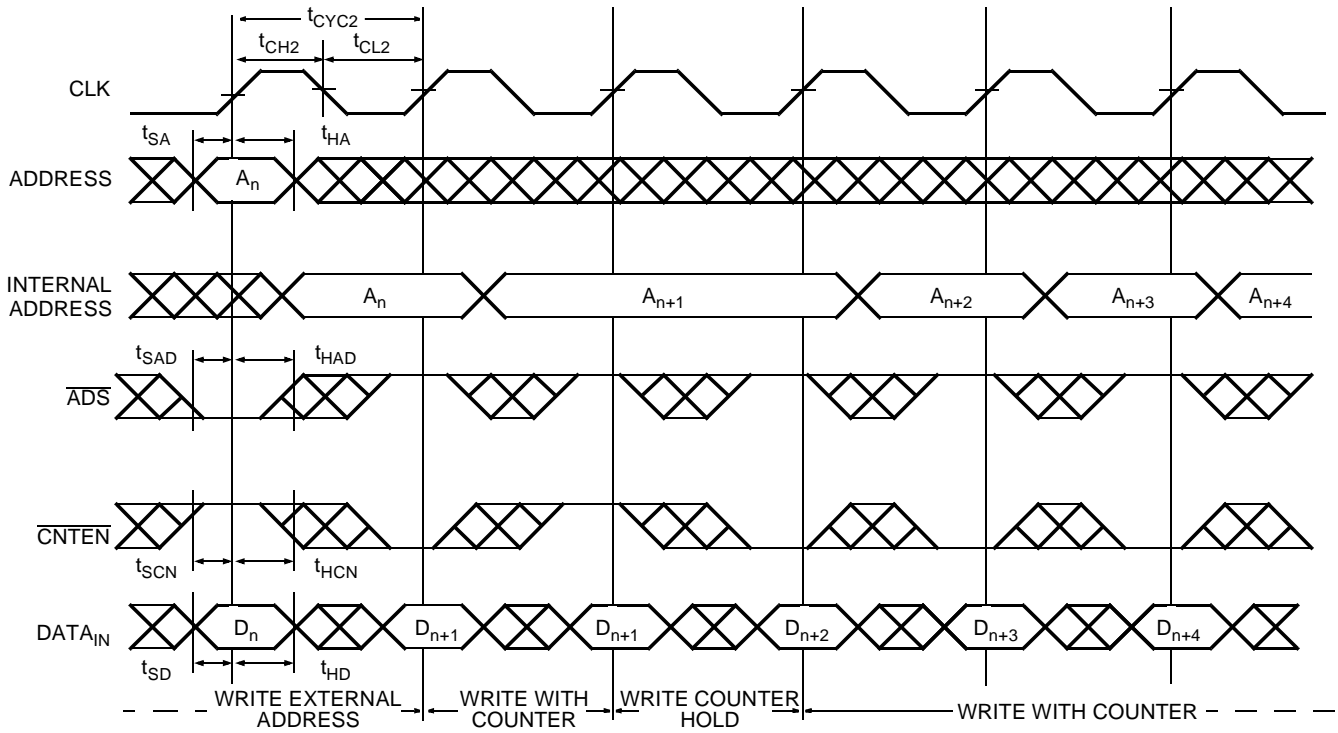
Switching Waveforms (continued)
Pipelined Read-to-Write-to-Read ($\overline{OE} = V_{IL}$)^[17,24,25,26]

Pipelined Read-to-Write-to-Read (\overline{OE} Controlled)^[17,24,25,26]

Notes:

24. Output state (HIGH, LOW, or High-Impedance) is determined by the previous cycle control signals.
25. \overline{CE}_0 and $\overline{ADS} = V_{IL}$; \overline{CE}_1 , \overline{CNTEN} , and $\overline{CNTRST} = V_{IH}$.
26. During "No operation", data in memory at the selected address may be corrupted and should be re-written to ensure data integrity.

Switching Waveforms (continued)
Flow-Through Read-to-Write-to-Read ($\overline{OE} = V_{IL}$)^[15,17,25,26]

Flow-Through Read-to-Write-to-Read (\overline{OE} Controlled)^[15,17,24,25,26]


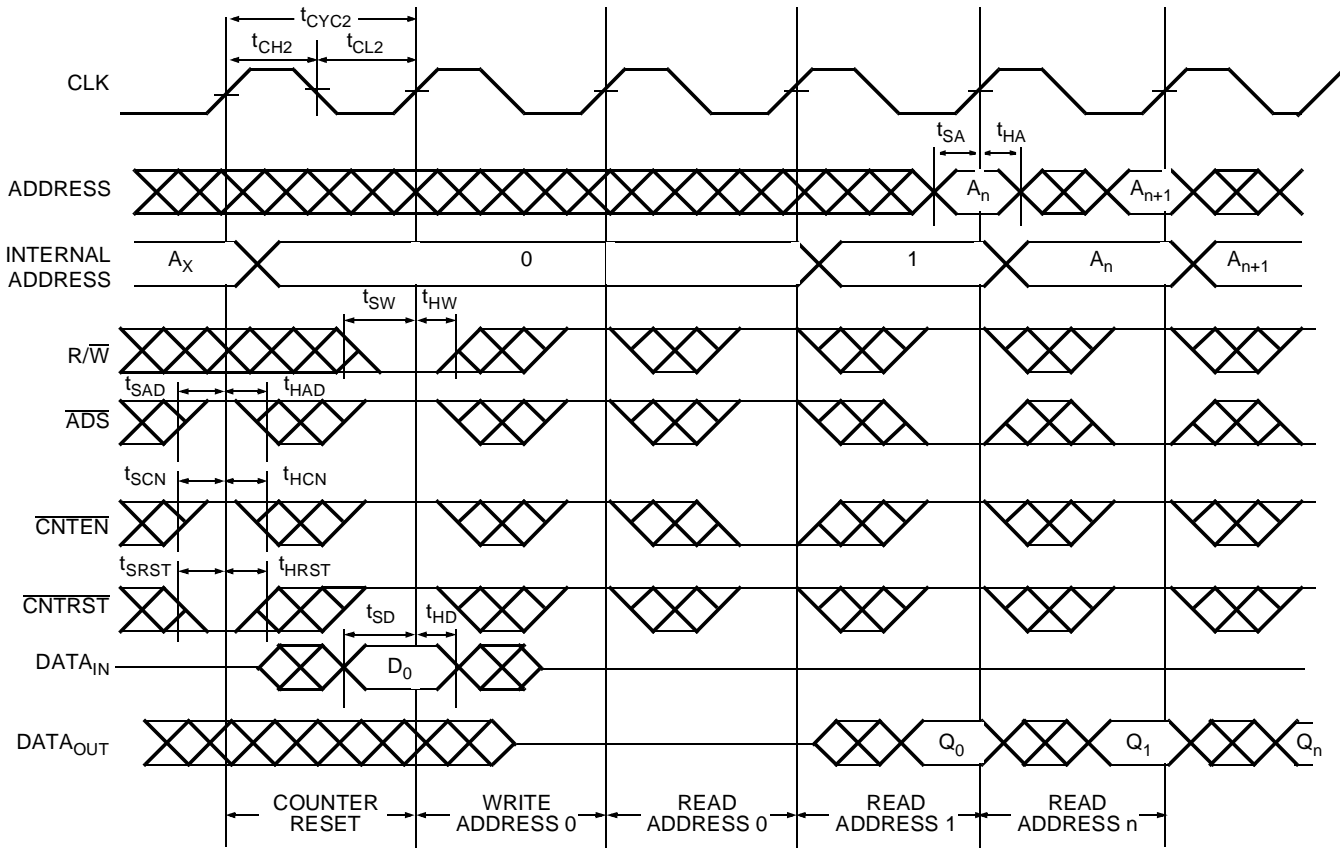
Switching Waveforms (continued)
Pipelined Read with Address Counter Advance^[27]

Flow-Through Read with Address Counter Advance^[27]

Note:

27. \overline{CE}_0 and $\overline{OE} = V_{IL}$; CE_1 , $R\overline{W}$ and $\overline{CNTRST} = V_{IH}$.

Switching Waveforms (continued)
Write with Address Counter Advance (Flow-Through or Pipelined Outputs)^[28,29]

Notes:

28. $\overline{CE_0}$, \overline{UB} , \overline{LB} , and $R/\overline{W} = V_{IL}$; CE_1 and $\overline{CNTEN} = V_{IH}$.





29. The "Internal Address" is equal to the "External Address" when $\overline{ADS} = V_{IL}$ and equals the counter output when $\overline{ADS} = V_{IH}$.

Switching Waveforms (continued)
Counter Reset (Pipelined Outputs)^[17,24,30,31]

Notes:





30. \overline{CE}_0 , \overline{UB} , and $\overline{LB} = V_{IL}$; $CE_1 = V_{IH}$.

31. No dead cycle exists during counter reset. A READ or WRITE cycle may be coincidental with the counter reset.

Read/Write and Enable Operation^[32,33,34]

Inputs					Outputs	Operation
\overline{OE}	CLK	\overline{CE}_0	CE_1	R/W	I/O ₀ –I/O ₁₇	
X		H	X	X	High-Z	Deselected ^[35]
X		X	L	X	High-Z	Deselected ^[35]
X		L	H	L	D _{IN}	Write
L		L	H	H	D _{OUT}	Read ^[35]
H	X	L	H	X	High-Z	Outputs Disabled

Address Counter Control Operation^[32,36,37,38]

Address	Previous Address	CLK	\overline{ADS}	\overline{CNTEN}	\overline{CNTRST}	I/O	Mode	Operation
X	X		X	X	L	D _{out(0)}	Reset	Counter Reset to Address 0
A _n	X		L	X	H	D _{out(n)}	Load	Address Load into Counter
X	A _n		H	H	H	D _{out(n)}	Hold	External Address Blocked—Counter Disabled
X	A _n		H	L	H	D _{out(n+1)}	Increment	Counter Enabled—Internal Address Generation

Notes:

32. "X" = Don't Care, "H" = V_{IH}, "L" = V_{IL}.
33. \overline{ADS} , \overline{CNTEN} , \overline{CNTRST} = Don't Care.
34. \overline{OE} is an asynchronous input signal.
35. When \overline{CE} changes state. In the pipelined mode, deselection and read happen in the following clock cycle.
36. \overline{CE}_0 and \overline{OE} = V_{IL}; CE_1 and R/W = V_{IH}.
37. Data shown for flow-through mode; pipelined mode output will be delayed by one cycle.
38. Counter operation is independent of \overline{CE}_0 and CE_1 .



Ordering Information

16K x16 3.3V Synchronous Dual-Port SRAM

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
7.5 ^[1]	CY7C09269V-7AC	A100	100-Pin Thin Quad Flat Pack	Commercial
9	CY7C09269V-9AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09269V-9AI	A100	100-Pin Thin Quad Flat Pack	Industrial
12	CY7C09269V-12AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09269V-12AI	A100	100-Pin Thin Quad Flat Pack	Industrial

Shaded area contains advance information.

32K x16 3.3V Synchronous Dual-Port SRAM

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
7.5 ^[1]	CY7C09279V-7AC	A100	100-Pin Thin Quad Flat Pack	Commercial
9	CY7C09279V-9AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09279V-9AI	A100	100-Pin Thin Quad Flat Pack	Industrial
12	CY7C09279V-12AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09279V-12AI	A100	100-Pin Thin Quad Flat Pack	Industrial

Shaded area contains advance information.

64K x16 3.3V Synchronous Dual-Port SRAM

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
7.5 ^[1]	CY7C09289V-7AC	A100	100-Pin Thin Quad Flat Pack	Commercial
9	CY7C09289V-9AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09289V-9AI	A100	100-Pin Thin Quad Flat Pack	Industrial
12	CY7C09289V-12AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09289V-12AI	A100	100-Pin Thin Quad Flat Pack	Industrial

Shaded area contains advance information.

16K x18 3.3V Synchronous Dual-Port SRAM

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
7.5 ^[1]	CY7C09369V-7AC	A100	100-Pin Thin Quad Flat Pack	Commercial
9	CY7C09369V-9AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09369V-9AI	A100	100-Pin Thin Quad Flat Pack	Industrial
12	CY7C09369V-12AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09369V-12AI	A100	100-Pin Thin Quad Flat Pack	Industrial

Shaded area contains advance information.

32K x18 3.3V Synchronous Dual-Port SRAM

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
7.5 ^[1]	CY7C09379V-7AC	A100	100-Pin Thin Quad Flat Pack	Commercial
9	CY7C09379V-9AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09379V-9AI	A100	100-Pin Thin Quad Flat Pack	Industrial
12	CY7C09379V-12AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09379V-12AI	A100	100-Pin Thin Quad Flat Pack	Industrial

Shaded area contains advance information.

Ordering Information (continued)

64K x18 3.3V Synchronous Dual-Port SRAM

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
7.5 ^[1]	CY7C09389V-7AC	A100	100-Pin Thin Quad Flat Pack	Commercial
9	CY7C09389V-9AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09389V-9AI	A100	100-Pin Thin Quad Flat Pack	Industrial
12	CY7C09389V-12AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C09389V-12AI	A100	100-Pin Thin Quad Flat Pack	Industrial

Shaded area contains advance information.

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Package Diagram
100-Pin Thin Plastic Quad Flat Pack (TQFP) A100
